

L660-__ __V High Bright Red LED Lamp

This series of L660-__ __V is an AlGaAs LED mounted on a lead frame with a clear epoxy lens. On forward bias, it emits a band of visible light that peaks 660nm.

1) Specifications

- (1) Chip material AlGaAs/AlGaAs
- (2) Peak wavelength 660nm typ.
- (3) Package Clear epoxy resin
- (4) Lead frame Soldered

2) Absolute Maximum Ratings

Item	Symbol	Maximum Rated Value	Unit	Ambient Temperature
Power Dissipation	P _D	120	mW	T _a =25°C
Forward Current	I _F	50	mA	T _a =25°C
Reverse Voltage	V _R	5	V	T _a =25°C
Operating Temperature	T _{OPR}	-30 ~ +85	°C	T _a =25°C
Storage Temperature	T _{STG}	-30 ~ +100	°C	
Soldering Temperature	T _{SOL}	260	°C	

3) Electro-Optical Characteristics [T_a=25°C]

Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	V _F	I _F =20mA		1.9	2.3	V
Reverse Current	I _R	V _R =5V			10	uA
Total Radiated Power	P _O	I _F =20mA		4.5		mW
Peak Wavelength	λ _P	I _F =20mA	650	660	670	nm
Half Width	Δλ	I _F =20mA		20		nm

4) Characteristics of Brightness [T_a=25°C]

Type	Viewing Half Angle	Brightness I _F =20mA unit: mcd			Outer Dimension	
		Minimum	Typical	Maximum	Dimension	Figure
L660-01V	±10°		2000		Φ5	1
L660-02V	±6°		4000		Φ5	2
L660-03V	±12°		1300		Φ5	3
L660-04V	±15°		750		Φ5	4
L660-05V	±30°		150		Φ5	5
L660-06V	±6°		4000		Φ5	6
L660-09V	±25°(Long)		900		Φ5	7
	±15°(Short)			Oval		
L660-10V	±5°		6000*		Φ10	8
L660-33V	±15°		800		Φ3	9
L660-36V	±30°		500		Φ3	10

‡ Brightness is measured by Tektronix J-16.

‡ Total Radiated Power is measured by Photodyne #500.

‡ *Classification: U=4000mcd, V=6000mcd, W=8000mcd